HALOGEN FREE

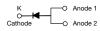


## Vishay General Semiconductor

# SMD Photovoltaic Solar Cell Protection Schottky Rectifier

Ultra Low  $V_F = 0.34 \text{ V}$  at  $I_F = 5 \text{ A}$ 





PRIMARY CHARACTERISTICS			
I <sub>F(AV)</sub>	10 A		
V <sub>RRM</sub>	45 V		
I <sub>FSM</sub>	180 A		
V <sub>F</sub> at I <sub>F</sub> = 10 A	0.41 V		
T <sub>OP</sub> max.	150 °C		
Package	TO-277A (SMPC)		
Diode variation	Single die		

### **FEATURES**

- Very low profile typical height of 1.1 mm
- Ideal for automated placement
- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

### TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

### **MECHANICAL DATA**

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V10P45S	UNIT	
Device marking code		1045S		
Maximum repetitive peak reverse voltage		45	V	
Maximum DC forward current	I <sub>F</sub> <sup>(1)</sup>	10	- A	
	I <sub>F</sub> <sup>(2)</sup>	4.4		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	180	А	
Junction temperature in DC forward current without reverse bias, $t \le 1 \text{ h}$	T <sup>J</sup> (3)	≤ 200	°C	
Operating junction temperature range	T <sub>OP</sub>	-40 to +150	°C	
Storage temperature range	T <sub>STG</sub>	-40 to +175	°C	

### Notes

- (1) Mounted on 30 mm x 30 mm aluminum PCB
- (2) Free air, mounted on recommended copper pad area
- (3) Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage	I <sub>F</sub> = 5.0 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.42	-	V
	I <sub>F</sub> = 10 A			0.48	0.57	
	I <sub>F</sub> = 5.0 A	T <sub>A</sub> = 125 °C		0.34	-	
	I <sub>F</sub> = 10 A			0.41	0.50	
Reverse current	V <sub>R</sub> = 45 V	T <sub>A</sub> = 25 °C	lp (2)	21	800	μΑ
	$V_R = 45 V$ $T_A = 125$	T <sub>A</sub> = 125 °C		9	35	mA

#### **Notes**

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V10P45S	UNIT	
Tunical thormal registance	R <sub>0JA</sub> (1)	75	°C/W	
Typical thermal resistance	R <sub>0JM</sub> (2)	4		

#### **Notes**

- $^{(1)}$  Free air, mounted on recommended copper pad area; thermal resistance  $R_{\theta JA}$  junction to ambient
- (2) Mounted on 30 mm x 30 mm aluminum PCB; thermal resistance R<sub>0,IM</sub> junction to mount

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
V10P45S-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel	
V10P45S-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel	

## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

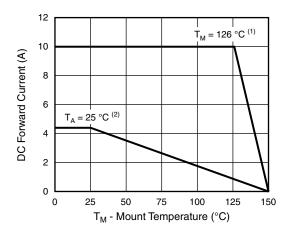


Fig. 1 - Forward Current Derating Curve

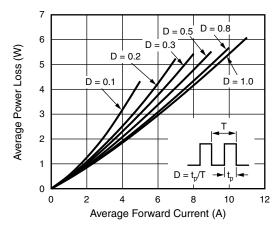


Fig. 2 - Forward Power Loss Characteristics

### Notes

- $^{(1)}$  Mounted on 30 mm x 30 mm aluminum PCB; T<sub>M</sub> measured at the terminal of cathode band (R<sub>0JM</sub> = 4 °C/W)
- $^{(2)}$  Free air, mounted on recommended copper pad area  $(R_{\theta JA} = 75~^{\circ}\text{C/W})$



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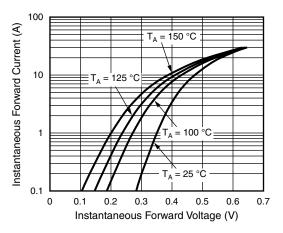


Fig. 3 - Typical Instantaneous Forward Characteristics

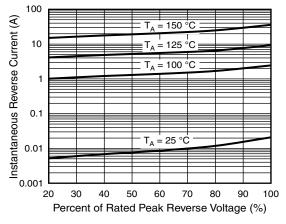


Fig. 4 - Typical Reverse Leakage Characteristics

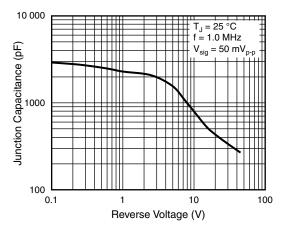


Fig. 5 - Typical Junction Capacitance

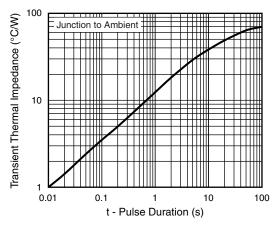
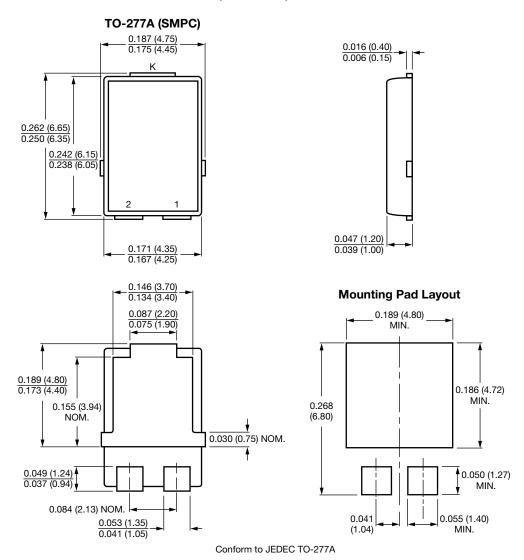


Fig. 6 - Typical Transient Thermal Impedance



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## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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